

NPN Triple Diffused Planar Silicon Transistor

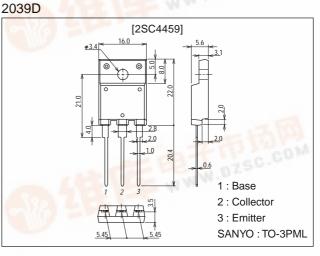


Features

- · High breakdown voltage, high reliability.
- · Fast switching speed.
- \cdot Wide ASO.
- · Adoption of MBIT process.
- Micaless package facilitating mounting.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		800	V
Collector-to-Emitter Voltage	VCEO		500	V
Emitter-to-Base Voltage	V _{EBO}		7	V
Collector Current	۱ _C		-10	A
Collector Current (Pulse)	ICP	PW≤300µs, duty cycle≤10%	20	A
Base Current	Ι _Β		3	A
Collector Dissipation	PC		3	W
		Tc=25°C	50	W
Junction Temperature	Тј		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Onit
Collector Cutoff Current	ICBO	V _{CB} =500V, I _E =0		1.Fr	10	μΑ
Emitter Cutoff Current	IEBO	V _{EB} =5V, I _C =0	28-		10	μA
DC Current Gain	h _{FE} 1	V _{CE} =5V, I _C =0.8A	15*	10.10	50*	
	h _{FE} 2	V _{CE} =5V, I _C =4A	8			

* : For the h_{FE} 1 of the 2SC4459, specify two ranks or more in principle.

15 L 30 20 M 40 30 N 50

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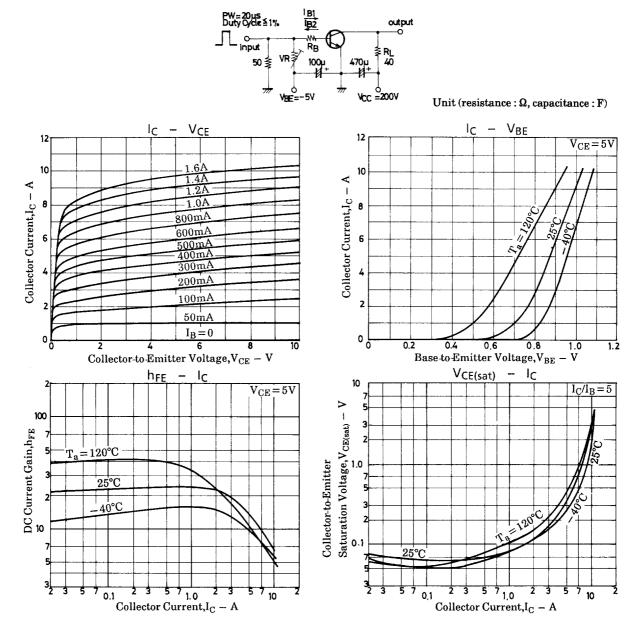
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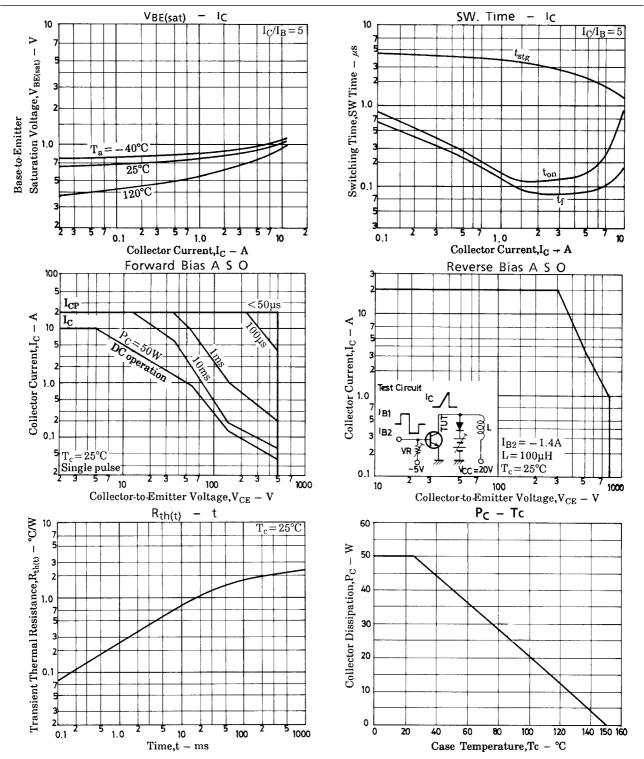
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Parameter	Symbol	Conditions		Ratings		
			min	typ	max	Unit
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =0.8A		18		MHz
Output Capacitance	C _{ob}	V _{CB} =10V, f=1MHz		50		pF
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	IC=4A, IB=0.8A			1.0	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =4A, I _B =0.8A			1.5	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =1mA, I _E =0	800			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =5mA, R _{BE} =∞	500			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =1mA, I _C =0	7			V
Collector-to-Emitter Sustain Voltage	V _{CEX(sus)}	I _C =3.5A, I _{B1} =-I _{B2} =1.4A, L=500µH, Clamped	500			V
Turn-ON Time	ton	V_{CC} =200V, 5I _{B1} =-2.5I _{B2} =I _C =5A, R _L =40 Ω			0.5	μs
Storage Time	tstg	V_{CC} =200V, 5I _{B1} =-2.5I _{B2} =I _C =5A, R _L =40 Ω			3.0	μs
Fall Time	tf	V _{CC} =200V, 5I _{B1} =-2.5I _{B2} =I _C =5A, R _L =40Ω			0.3	μs

Switching Time Test Circuit



2SC4459



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